



## Power Supply Input

Var	Value	Units	Description
VACMIN	100	V	Minimum Input AC Voltage (Manual Overwrite)
VACMAX	265	V	Maximum Input AC Voltage (Manual Overwrite)
FL	50	Hz	Line Frequency (Manual Overwrite)
TC	2.52	ms	Input Rectifier Conduction Time
Z	0.47		Loss Allocation Factor
$\eta$	85.0	%	Efficiency Estimate (Target)
VMIN	100.5	V	Minimum DC Input Voltage
VMAX	374.8	V	Maximum DC Input Voltage

## Input Section

Var	Value	Units	Description
Fuse	1.25	A	Input Fuse Rated Current
I AVG	0.20	A	Average Diode Bridge Current (DC Input Current)

## Device Variables

Var	Value	Units	Description
Device	TOP264EG		PI Device Name
BVDSS	725	V	Drn-Src Bkdn Voltage
Current Limit Mode	Default		Device Current Limit Mode
OVP_FLAG	NO		Output Overvoltage Protection Enabled
PO	16.87	W	Total Output Power
VDRAIN Estimated	534.77	V	Estimated Drain Voltage
VDS	5.38	V	On state Drain to Source Voltage
FS	132000	Hz	Switching Frequency (at VMIN and Full Load)
KP	0.527		Continuous/Discontinuous Operating Ratio (at VMIN and Full Load)
DMAX	0.587		Maximum Duty Cycle (at VMIN and Full Load)
KI	1.00		Current Limit Reduction Factor
ILIMITEXT	1.21	A	Programmed Current Limit
ILIMITMIN	1.209	A	Minimum Current Limit
ILIMITMAX	1.391	A	Maximum Current Limit
PLIM_FLAG	NO		Enable Overload Power Limiting
IP	0.457	A	Peak Primary Current (at VMIN and Full Load)
IRMS	0.263	A	Primary RMS Current (at VMIN and Full Load)
RTH_DEVICE	82.63	°C/W	PI Device Heatsink Maximum Thermal Resistance
DEV_HSINK_TYPE	Custom Aluminum		PI Device Heatsink Type
DEV_HSINK_AREA	400	mm <sup>2</sup>	PI Device Heatsink Area

## Clamp Circuit

Var	Value	Units	Description
Clamp Type	Zener Clamp		Clamp Circuit Type

VCLAMP	25.00	V	Average Clamping Voltage
Estimated Clamp Loss	0.000	W	Clamp total power loss
VC_MARGIN	115.23	V	Clamp Voltage Safety Margin

### Primary Bias Variables

Var	Value	Units	Description
VB	12.0	V	Bias Voltage
IB	0.006	A	Bias Current
PIVB	51	V	Bias Rectifier Maximum Peak Inverse Voltage
NB	9		Primary Bias Winding Number of Turns

### Transformer Construction Parameters

Var	Value	Units	Description
Core Type	EFD15 (EFD15/8/5-3F3-S)		Core Type (Manual Overwrite)
Core Material	3F3		Core Material
Primary Pins	4		Number of Primary pins used
Secondary Pins	2		Number of Secondary pins used
USE_SHIELDS	NO		Use shield Windings
LP_nom	1829	$\mu H$	Nominal Primary Inductance
LP_Tol	10.0	%	Primary Inductance Tolerance
NP	86.2		Calculated Primary Winding Total Number of Turns
NSM	16		Secondary Main Number of Turns
Primary Current Density	5.33	A/mm <sup>2</sup>	Primary Winding Current Density
VOR	135.00	V	Reflected Output Voltage
BW	8.85	mm	Bobbin Winding Width
FF	127.04	%	Actual Transformer Fit Factor. 100% signifies fully utilized winding window. See Warnings section for detail
AE	15.00	mm <sup>2</sup>	Core Cross Sectional Area
ALG	222	nH/T <sup>2</sup>	Gapped Core Specific Inductance
BM	582	mT	Maximum Flux Density. See Errors section for detail
BP	1953	mT	Peak Flux Density. See Errors section for detail
BAC	154	mT	AC Flux Density for Core Loss
LG	0.061	mm	Estimated Gap Length. See Information section for detail
L_LKG	54.87	$\mu H$	Estimated primary leakage inductance
LSEC	20	nH	Secondary Trace Inductance

### Primary Winding Section 1

Var	Value	Units	Description
NP1	87		Number of Primary Winding Turns in the First Section of Primary
L	2.90		Primary Winding - Number of Layers
DC Copper Loss	0.06	W	Primary Section 1 DC Losses

### Output 1

Var	Value	Units	Description
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VO	24.00	V	Typical Output Voltage
IO	0.70	A	Output Current
VOUT_ACTUAL	24.00	V	Actual Output Voltage
NS	16		Secondary Number of Turns
L_S_OUT	1.08		Secondary Output Winding Layers
DC Copper Loss	0.13	W	Secondary DC Losses
VD	1.07	V	Output Winding Diode Forward Voltage Drop
VD	1.07	V	Output Winding Diode Forward Voltage Drop
PIVS	92.92	V	Output Rectifier Maximum Peak Inverse Voltage
ISP	2.452	A	Peak Secondary Current
ISRMS	1.185	A	Secondary RMS Current
ISRMS_WINDING	1.185	A	Secondary Winding RMS Current
Secondary Current Density	9	A/mm <sup>2</sup>	Secondary Winding Current Density
RTH_RECTIFIER	72.26	°C/W	Output Rectifier Heatsink Maximum Thermal Resistance
OR_HSINK_TYPE	2 Oz (70 μ) 2-Sided Copper PCB		Output Rectifier Heatsink Type
OR_HSINK_AREA	52	mm <sup>2</sup>	Output Rectifier Heatsink Area
CO	220 x 1	μF	Output Capacitor - Capacitance
IRIPPLE	0.956	A	Output Capacitor - RMS Ripple Current
Expected Lifetime	25301	hr	Output Capacitor - Expected Lifetime

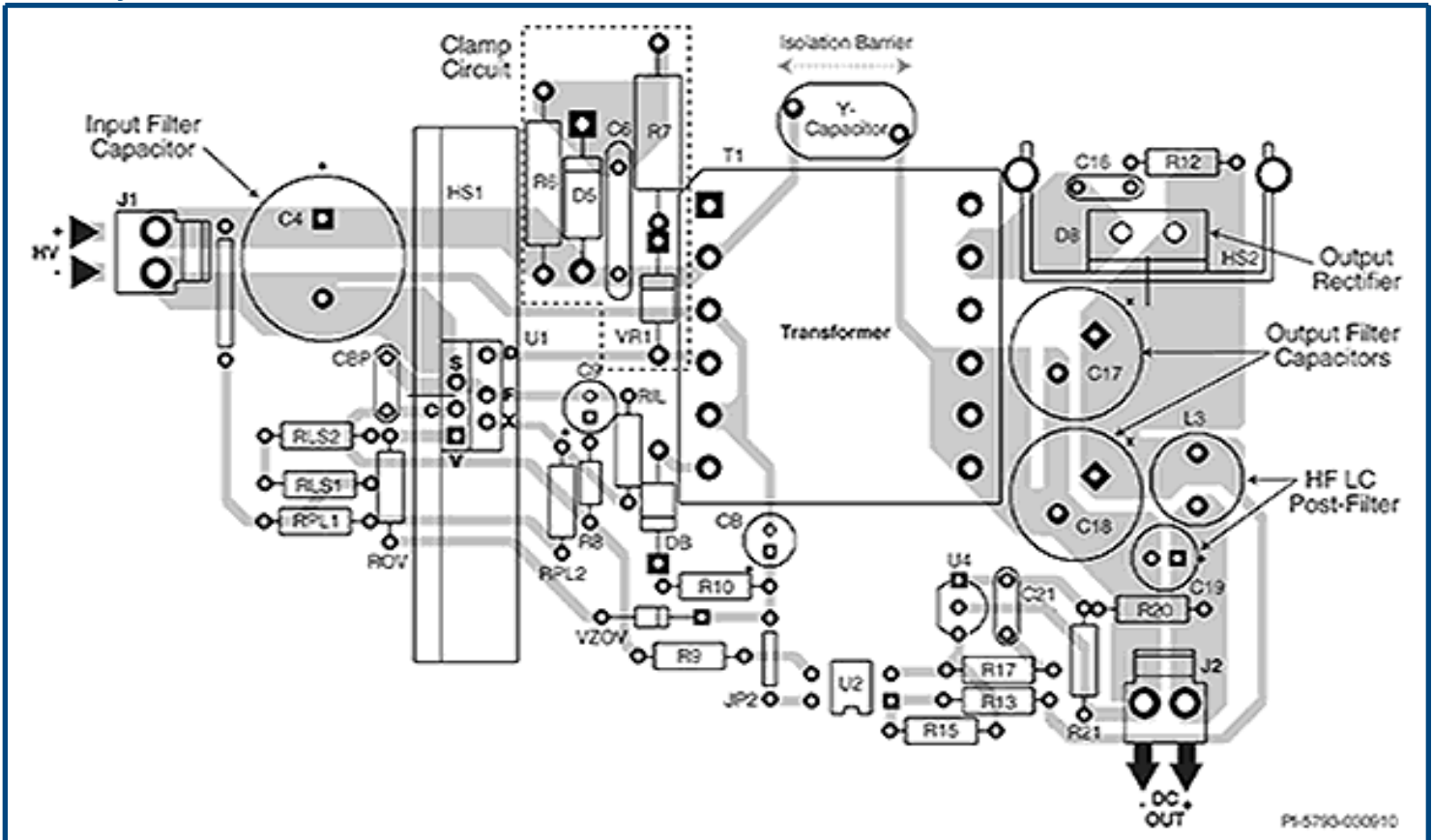
### Feedback Circuit

Var	Value	Units	Description
DUAL_OUTPUT_FB_FLAG	NO		Get feedback from 2 outputs
SF_FLAG	NO		Soft Finish Circuits use flag
TYPE_3CTRL_FLAG	YES		Phase Boost Network flag

The regulation and tolerances do not account for thermal drifting and component tolerance of the output diode forward voltage drop and voltage drops across the LC post filter. The actual voltage values are estimated at full load only.

Please verify cross regulation performance on the bench.

## Board Layout Recommendations



Click on the "Show me" icon to highlight relevant areas on the sample layout.

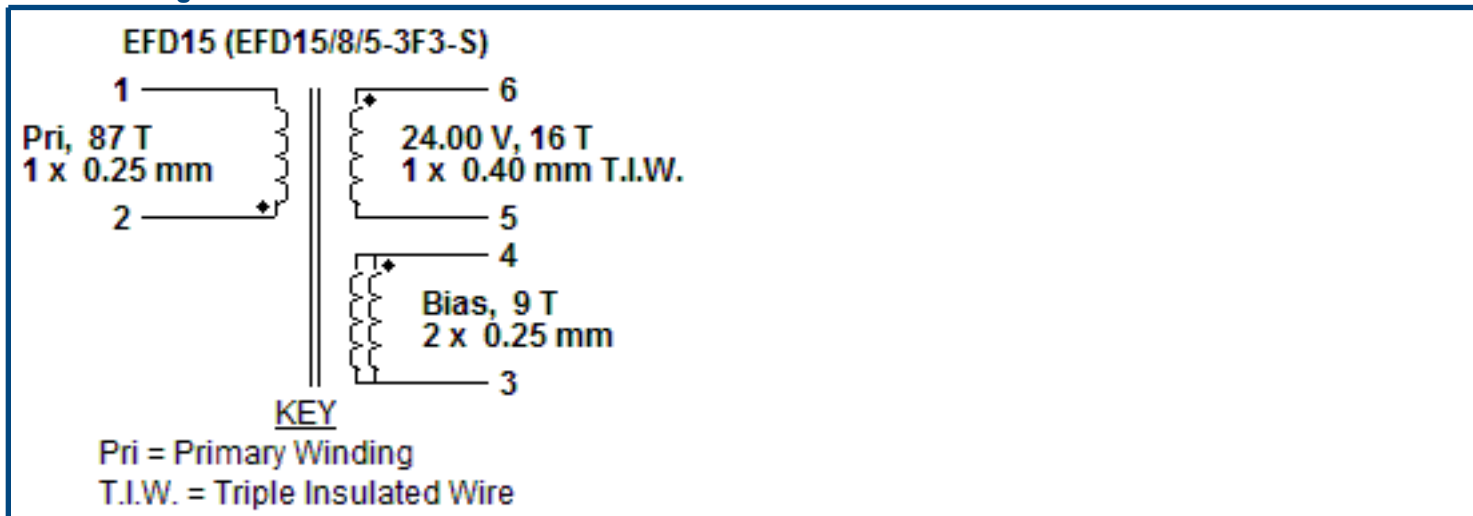
	Description	Show Me
1	Minimize loop area formed by drain, clamp and transformer	
2	Bias winding and bias capacitor are a power connection and therefore returned to Kelvin connection at SOURCE pin	
3	V and X pin node areas minimized, line sensing (R1 & R2) and power limiting (R3 & R4) close to device. Connections to V and X pin nodes should be away from noisy switching nodes (drain, clamp and bias)	
4	Place CONTROL pin decoupling capacitor directly across CONTROL and SOURCE pins	
5	Y capacitor connected between output RTN and B+	
6	Minimize loop area formed by secondary winding, the output rectifier and the output filter capacitor	
7	Kelvin connection at SOURCE pins: power and signal currents kept separate	
8	B+ connection of RLS or RPL resistor should be on input side of capacitor to prevent switching noise injection	

## Bill Of Materials

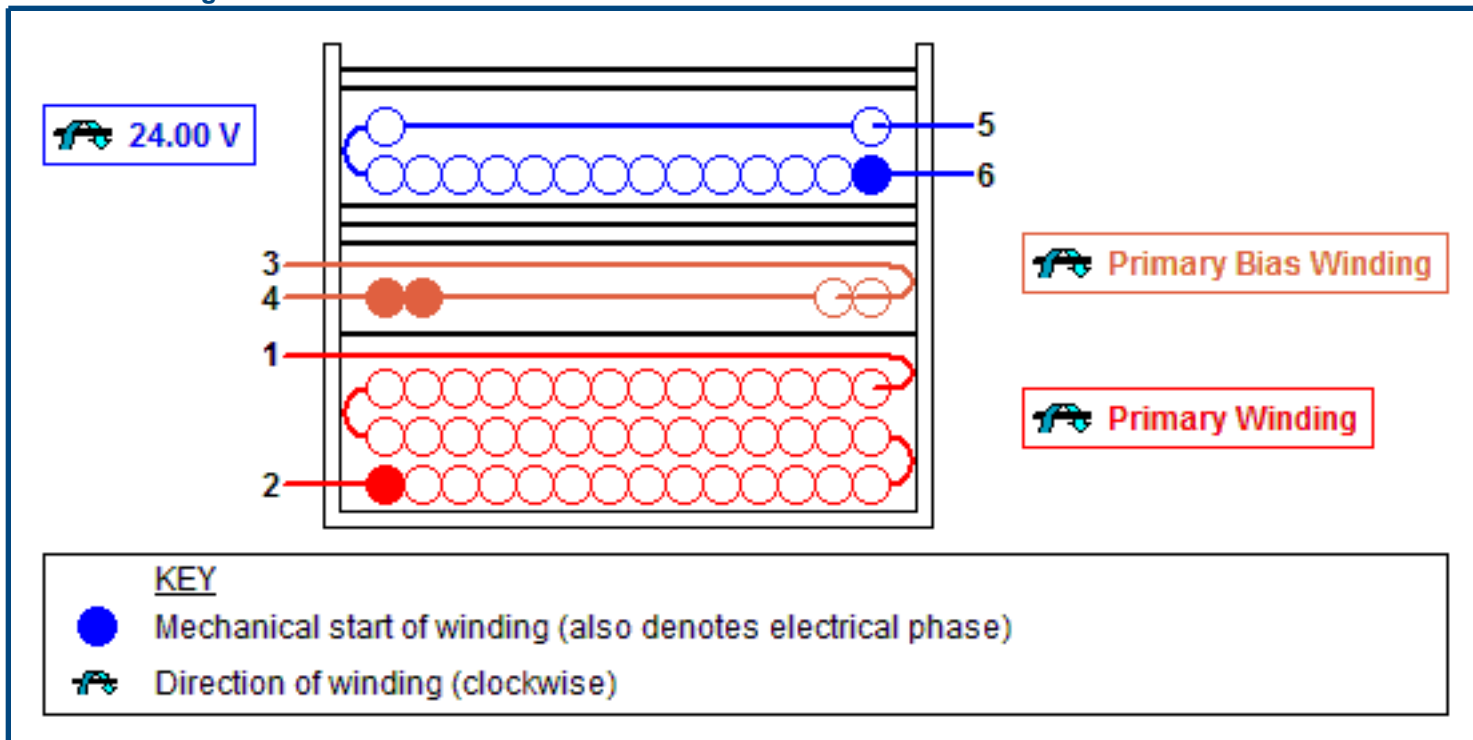
<b>Ite m #</b>	<b>Quantity</b>	<b>Part Ref</b>	<b>Value</b>	<b>Description</b>	<b>Mfg</b>	<b>Mfg Part Number</b>
1	2	C1, C2	15 $\mu$ F	15 $\mu$ F, 400 V, High Voltage Al Electrolytic, (22 mm x 12.5 mm)	Nichicon	UCS2G150MHD1TO
2	1	C3	0.1 $\mu$ F	0.1 $\mu$ F, 50 V, Ceramic, X7R	Kemet	C322C104K5R5TA
3	1	C4	47 $\mu$ F	47 $\mu$ F, 10.0 V, Electrolytic, Gen Purpose, 2300 m $\Omega$ , (11 mm x 4 mm)	Nichicon	UPW1A470MDD6
4	1	C5	0.15 nF	0.15 nF, 250 VAC, Ceramic, Y Class	TDK	CD70-B2GA151KYNS
5	1	C6	27 pF	27 pF, 1 kV, High Voltage Ceramic	Vishay	S270K25SL0N63L6R
6	1	C7	10 $\mu$ F	10 $\mu$ F, 50 V, Electrolytic, Gen Purpose, 1050 m $\Omega$ , (11.5 mm x 5 mm)	Panasonic	ECA-1HHG100
7	1	C8	220 $\mu$ F	220 $\mu$ F, 35 V, Electrolytic, Super Low ESR, 56 m $\Omega$ , (15 mm x 8 mm)	United Chemi-Con	EKZE350ELL221MH15D
8	1	C9	100 $\mu$ F	100 $\mu$ F, 35 V, Electrolytic, Low ESR, 180 m $\Omega$ , (15 mm x 6.3 mm)	United Chemi-Con	ELXZ350ELL101MF15D
9	1	C10	8.2 nF	8.2 nF, 50 V, Ceramic, X7R	Kemet	C315C822K5R5TA
10	1	C11	33 nF	33 nF, 50 V, Ceramic, X7R	Kemet	C315C333K5R5TA
11	4	D1, D2, D3, D4	1N4006-E3/54	800 V, 1 A, Standard Recovery, DO-41	Vishay	1N4006-E3/54
12	1	D5	RMPG06K-E3/54	800 V, 1 A, Fast Recovery, 250 ns, MPG06	Vishay	RMPG06K-E3/54
13	1	D6	1N4148	100 V, 0.15 A, Fast Recovery, 8 ns, DO-35	Vishay	1N4148
14	1	D7	BYV27-200-TR	200 V, 2 A, Ultrafast Recovery, 25 ns, SOD57	Vishay	BYV27-200-TR
15	1	F1	1.25 A	250 VAC, 1.25 A, Radial TR5, Time Lag Fuse	Littelfuse / Wickmann(R)	37411250410
16	1	HS1		10 mm x 20 mm. Aluminum Alloy (3003 OR 5052), 1.6 mm thickness. Heatsink for use with Device U1.	Custom	
17	1	L1	6 mH	6 mH, 1.6 A	Panasonic	ELF18N016
18	1	L2	3.3 $\mu$ H	3.3 $\mu$ H, 2.66 A	Bourns Inc.	RL822-3R3K-RC
19	2	R1, R2	2.37 M $\Omega$	2.37 M $\Omega$ , 1 %, 0.25 W, Metal Film	Generic	
20	1	R3	6.8 $\Omega$	6.8 $\Omega$ , 5 %, 0.125 W, Carbon Film	Generic	
21	1	R4	390 $\Omega$	390 $\Omega$ , 5 %, 0.25 W, Carbon Film	Generic	
22	1	R5	15000 $\Omega$	15000 $\Omega$ , 1 %, 0.125 W, Metal Film	Generic	
23	1	R6	1690 $\Omega$	1690 $\Omega$ , 1 %, 0.125 W, Metal Film	Generic	
24	1	R7	1 k $\Omega$	1 k $\Omega$ , 5 %, 0.125 W, Carbon Film	Generic	
25	1	R8	97.6 k $\Omega$	97.6 k $\Omega$ , 1 %, 0.125 W, Metal Film	Generic	
26	1	R9	11.3 k $\Omega$	11.3 k $\Omega$ , 1 %, 0.125 W, Metal Film	Generic	
27	1	T1	EFD15 (EFD15/8/5-3F3-S)	3F3 Core Material Refer to Manufacturer datasheet for a number of parts to purchase	Ferroxcube	EFD15/8/5-3F3-S
28	1	T1 Bobbin	EFD15/8/5 - 2 (P4-S4)	Bobbin Material : Phenolformaldehyde (PF)	Ferroxcube	CSH-EFD15-1S-8P
29	1	T1 Core Acc.1	B66414	Yoke . Stainless spring steel (0.25 mm)	EPCOS (TDK)	B66414
30	1	T1 Core Acc.2	CLM-EFD15	Clamp . Stainless steel (CrNi)	Ferroxcube	CLM-EFD15

31	1	T1 Core Acc.3	CLI-EFD15	Clip . Stainless steel (CrNi)	Ferroxcube	CLI-EFD15
32	1	U1	TOP264EG	TOPSwitch-JX, TOP264EG, eSIP-7C	Power Integrations	TOP264EG
33	1	U2	PS2505-1-A	Optocoupler PS2505-1-A, 80 V, CTR 300 - 600 %, 4-DIP	Renesas	PS2505-1-A
34	1	U3	TL431CLPM	2.495 V, Shunt Regulator IC, 2 %, TO-92	Texas Instruments	TL431CLPM
35	1	VR1	P6KE160A-E3/54	160 V, 5 W, 5 %, DO-204AC, TVS	Vishay	P6KE160A-E3/54
36	1			52 mm <sup>2</sup> area on Copper PCB. 2 oz (70 μm) thickness. Heatsink for use with Rectifier D7.	Custom	

## Electrical Diagram



## Mechanical Diagram



## Winding Instruction

### Primary Winding

Start on pin(s) 2 and wind 87 turns (x 1 filar) of item [5]. in 3 layer(s) from left to right. Winding direction is clockwise. At the end of 1st layer, continue to wind the next layer from right to left. At the end of 2nd layer, continue to wind the next layer from left to right. On the final layer, spread the winding evenly across entire bobbin. Finish this winding on pin(s) 1.

Add 1 layer of tape, item [3], for insulation.

### Primary Bias Winding

Start on pin(s) 4 and wind 9 turns (x 2 filar) of item [5]. Winding direction is clockwise. Spread the winding evenly across entire bobbin. Finish this winding on pin(s) 3.

Add 3 layers of tape, item [3], for insulation.

### Secondary Winding

Start on pin(s) 6 and wind 16 turns (x 1 filar) of item [6]. Spread the winding evenly across entire bobbin. Winding direction is clockwise. Finish this winding on pin(s) 5.

Add 2 layers of tape, item [3], for insulation.

### Core Assembly

Assemble and secure core halves. Item [1].



## Varnish

Dip varnish uniformly in item [4]. Do not vacuum impregnate.

## Comments

1. For non margin wound transformers use triple insulated wire for all secondary windings.

## Materials

Item	Description
[1]	Core: EFD15 (EFD15/8/5-3F3-S), 3F3, gapped for ALG of 222 nH/T <sup>2</sup>
[2]	Bobbin: Generic, 4 pri. + 4 sec.
[3]	Barrier Tape: Polyester film [1 mil (25 µm) base thickness], 8.85 mm wide
[4]	Varnish
[5]	Magnet Wire: 0.25 mm, Solderable Double Coated
[6]	Triple Insulated Wire: 0.4 mm

## Electrical Test Specifications

Parameter	Condition	Spec
Electrical Strength, VAC	60 Hz 1 second, from pins 1,2,3,4 to pins 5,6.	3000
Nominal Primary Inductance, µH	Measured at 1 V pk-pk, typical switching frequency, between pin 1 to pin 2, with all other Windings open.	1829
Tolerance, ±%	Tolerance of Primary Inductance	10.0
Maximum Primary Leakage, µH	Measured between Pin 1 to Pin 2, with all other Windings shorted.	54.87

Although the design of the software considered safety guidelines, it is the user's responsibility to ensure that the user's power supply design meets all applicable safety requirements of user's product.



	<b>Description</b>	<b>Fix</b>	<b>Ref. #</b>
	<i>Maximum flux density limit exceeded.</i>	<i>Increase transformer size, increase secondary turns (NS), increase reflected output voltage (VOR), increase KP, increase efficiency estimate (N).</i>	203
	<i>Peak flux density limit exceeded.</i>	<i>Increase transformer size, increase secondary turns (NS), reduce size of device (ILIM MIN), increase reflected output voltage (VOR), increase KP, reduce KI (TOPGX/HX only).</i>	215
	<i>Transformer windings do not fit in the winding window</i>	<i>Use a larger transformer</i>	712
	<i>Gap length too small.</i>	<i>Increase core size, increase secondary turns (NS), increase reflected output voltage (VOR), increase KP. Verify minimum size with magnetics vendor.</i>	216